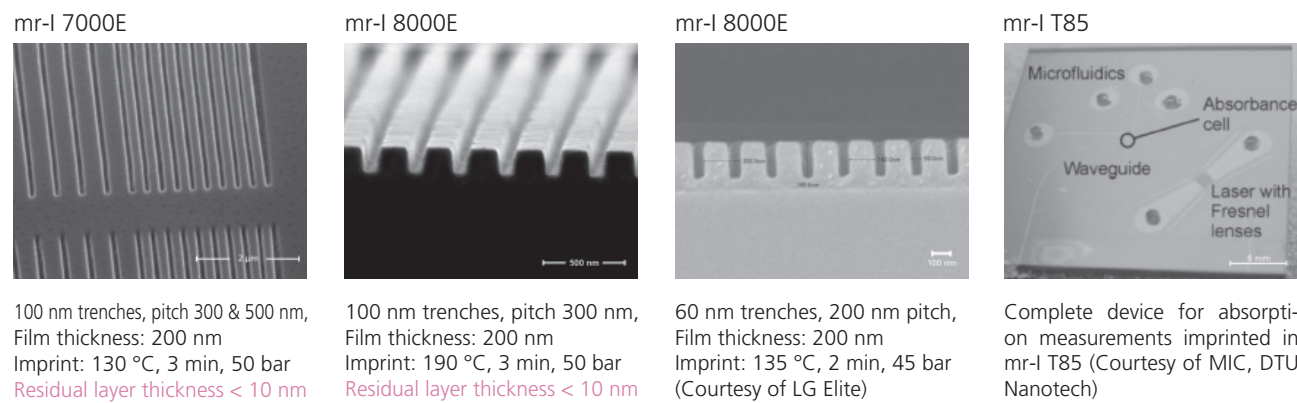


## Thermoplastics for Thermal Nanoimprint Lithography

Thermoplastic Polymer	mr-I 7000E	mr-I 8000E	mr-I T85	mr-I PMMA **
Glass transition temperature $T_g$	60 °C	115 °C	85 °C	105 °C
Imprint temperature	125 – 150 °C	170 – 190 °C	130 – 150 °C	150 – 180 °C
Imprint pressure	20 – 50 bar	20 – 50 bar	5 – 20 bar	20 – 50 bar
Ready-to-use solutions for various film thicknesses * (3000 rpm)	mr-I 7010E 100 nm mr-I 7020E 200 nm mr-I 7030E 300 nm	mr-I 8010E 100 nm mr-I 8020E 200 nm mr-I 8030E 300 nm	mr-I T85-0.3 300 nm mr-I T85-1.0 1.0 µm mr-I T85-5.0 5.0 µm	100 nm 300 nm 500 nm
Diluents	ma-T 1050	ma-T 1050	–	ma-T 1045

\* Different film thicknesses are available on request. \*\* Available with the low molecular weights 35k or 75k.



### mr-I 7000E & mr-I 8000E for pattern transfer

- Superior imprint characteristics:
  - Short cycle times due to fast polymer flow
  - Low imprint pressure
  - Low residual layer thickness
- High plasma etch resistance comparable to novolak-based photoresists

- #### Applications
- Etch mask for pattern transfer processes
  - Fabrication of nanopatterns for: mass data storage, nano-optical devices, sub-wavelength optical elements, photonic crystals, micro displays, LED

### mr-I T85 for lab-on-a-chip, micro-optics & bio applications

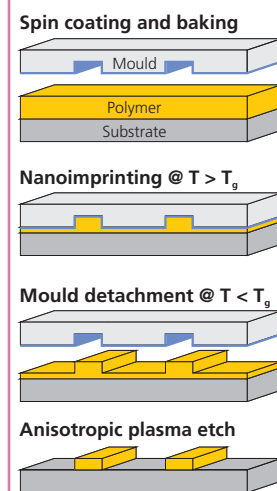
- Unpolar thermoplastic with very high chemical stability
- Beneficial flow behaviour during imprinting, low imprint pressure
- Excellent UV & optical transparency
- High plasma etch resistance comparable to novolak-based photoresists

- #### Applications
- Lab-on-a-chip systems
  - Bio applications
  - Fabrication of nano and micro-patterns for: micro-optical components, waveguides, microfluidics

### mr-I PMMA

- Low molecular weights (35k, 75k)
- For fundamental nanoimprint investigations

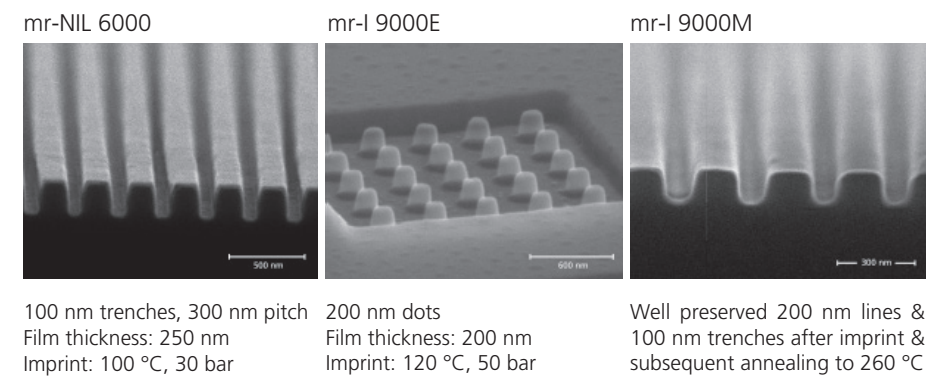
### NIL process Thermoplastics



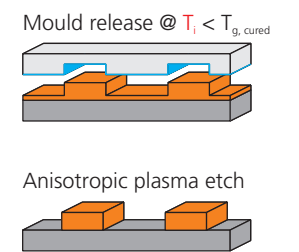
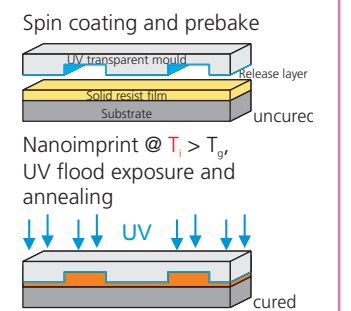
## Curing Polymers for Thermal Nanoimprint Lithography

Curing Polymer	mr-NIL 6000	mr-I 9000E	mr-I 9000M
Glass transition temperature <i>before curing</i>	40 °C	35 °C	35 °C
Imprint conditions	100 – 110 °C (isothermal process), 30 – 50 bar, UV exposure (broad band or i-line)	120 °C, 30 – 50 bar	100 °C, 30 – 50 bar, 2 <sup>nd</sup> imprint step at 140°C optional to increase thermal stability
Ready-to-use solutions for various film thicknesses * (3000 rpm)	mr-NIL 6000.1 100 nm mr-NIL 6000.2 200 nm mr-NIL 6000.3 300 nm	mr-I 9010E 100 nm mr-I 9020E 200 nm mr-I 9030E 300 nm	mr-I 9030M 300 nm mr-I 9050M 500 nm mr-I 9100M 1.0 µm
Diluents	ma-T 1045	ma-T 1045	ma-T 1045

\* Different film thicknesses are available on request.



### NIL process mr-NIL 6000



### mr-NIL 6000 high performance resist

- Combined thermal & UV nanoimprinting
- Short imprint cycle times, isothermal process: imprinting, UV flood exposure & mould release *at the same temperature*
- Very low residual layer thickness (<10 nm)
- Plasma etch resistance comparable to conventional novolak-based photoresists

- #### Applications
- Etch mask for pattern transfer processes
  - Permanent structures, e.g. in microfluidics or optics
  - Single & multilayer systems

### mr-I 9000E for pattern transfer

- Short imprint cycle times
- Thermal curing during imprint
- Very low residual layer thickness (<10 nm)
- Plasma etch resistance comparable to conventional novolak-based photoresists

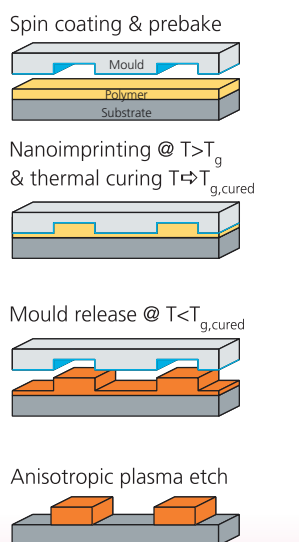
- #### Applications
- Etch mask for pattern transfer processes
  - Single & multilayer systems

### mr-I 9000M for micro & nanofabrication

- Simultaneous imprint of nano & micropatterns
- High thermal stability of imprinted patterns up to 260 °C
- Thermal curing during imprint
- Isothermal mould release

- #### Applications
- Permanent applications in micro & nanofabrication (e.g. nanoimprint mould)
  - Single & multilayer systems

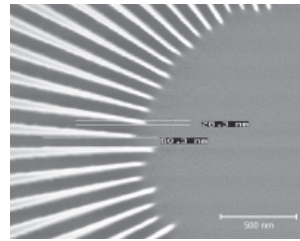
### NIL process mr-I 9000E & mr-I 9000M



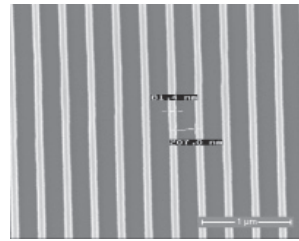
## UV-curable Polymers for UV-based Nanoimprint Lithography

UV-curable Polymer	mr-UVCur06	mr-UVCur21	mr-UVCur21SF
Coating method	Spin coating	Spin coating	Dispensing, spin coating
Process conditions	Imprint: room temperature process, low imprint pressures (>100 mbar), imprint in vacuum or under atmospheric pressure UV exposure: broad band or i-line, curing time few seconds		
Smallest feature size	50 nm	< 30 nm	< 30 nm
Aspect ratio	< 2	> 2	> 2
Ready-to-use solutions for various film thicknesses * (3000 rpm)	240 nm	100 nm 200 nm 300 nm	1.5 µm (spin coating)
Diluents	mr-T 1070	mr-T 1070	mr-T 1070
Adhesion Promoter	mr-APS1	mr-APS1	mr-APS1

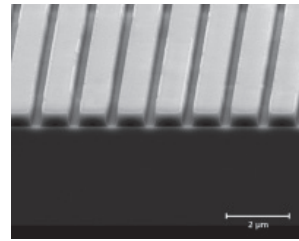
\* Different film thicknesses are available on request for mr-UVCur21.



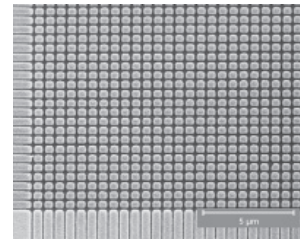
Imprinted lines, sub-30 nm resolution (Courtesy of AMO)



80 nm lines, pattern depth 110 nm (Courtesy of AMO)



300 nm trenches, residual layer thickness < 10 µm (Courtesy of Profactor)

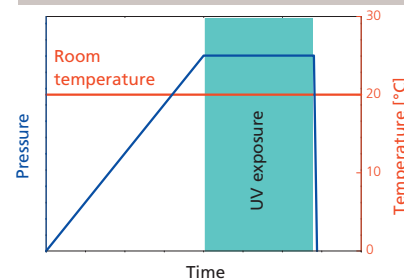


500 nm squares transferred into SiO<sub>2</sub> after imprinting, CHF<sub>3</sub> plasma (Courtesy of FSU Jena)

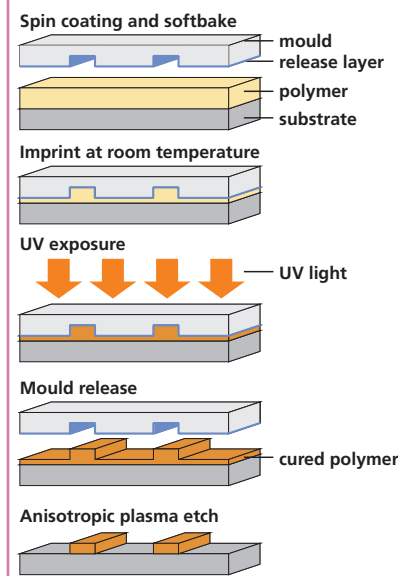
- Compatibility with various nanoimprint tools
- Wafer-scale or step & repeat imprints
- Superior imprint characteristics:
  - **Short cycle times** due to fast filling of mould cavities
  - Pattern **resolution below 30 nm** (mr-UVCur21, limited by the mould, not by the polymer)
  - **Very low residual layer** thickness (< 10 nm)
  - **Short curing times**, low UV doses, compatibility with various UV lamps and filter systems
- **High plasma etch resistance**, no residues after oxygen plasma etching

### Applications

- Etch mask for pattern transfer processes (dry and wet etching)
- Fabrication of nanopatterns
  - Data storage
  - Nano-optical devices, sub-wavelength optical elements
  - Photonic crystals
  - Micro and nanofluidics
  - Microelectronics



### UV-NIL process

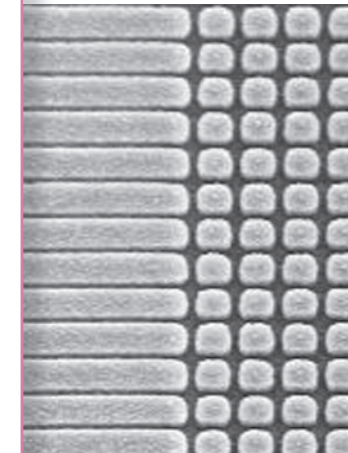


www.microresist.com

# micro resist technology

Gesellschaft für chemische Materialien spezieller Photoresistsysteme mbH

## Materials for Nanoimprint Lithography



### Polymers for thermal & UV-based nanoimprint lithography

- Thermoplastics
- Curing polymers (thermosets)
- UV-curable polymers

### Unique features of the nanoimprint polymers

- Excellent film quality
- Coating of various substrate materials, e.g. Si, SiO<sub>2</sub>, Al
- Attainable smallest feature size at least 50 nm (depending on mould resolution)
- Excellent pattern transfer fidelity
- Safe solvents

micro resist technology GmbH  
Köpenicker Str. 325  
12555 Berlin  
GERMANY

phone +49 30 65 76 21 92  
fax +49 30 65 76 21 93  
mail sales@microresist.de  
info www.microresist.com



www.microresist.com